

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Jack O. Chu, et al. **Examiner:** Unassigned
Serial No: To be assigned **Art Unit:** Unassigned
Filed: Herewith **Docket:** YOR920010308US3 (16315B)

For: EPITAXIAL AND POLYCRYSTALLINE GROWTH OF $Si_{1-x,y}Ge_xC_y$ AND $Si_{1-y}C_y$ ALLOY LAYERS ON Si BY UHV-CVD **Dated:** February 10, 2004

Commissioner for Patents
United States Patent Office
Alexandria, VA 23313-1450

PRELIMINARY AMENDMENT

Sir:

In connection with filing the above-identified application under 37 C.F.R. §1.53(b), applicants submit the following amendments and remarks for consideration by the Examiner and entry of record in the above-identified patent application.

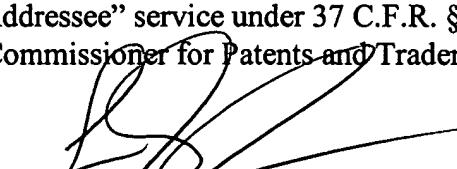
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Dated: February 10, 2004


Leslie S. Szivos, Ph.D.